

**Vishay Semiconductors** 

### Hyperfast Rectifier, 30 A FRED Pt<sup>®</sup>





2L TO-220AC Base cathode 2 C



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<u>ქ</u> 3 Ó Cathode Anode VS-ETH3006-M3

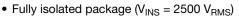
Cathode Anode VS-ETH3006FP-M3

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PRODUCT SUMMARY					
Package	2L TO-220AC, 2L TO-220FP				
I <sub>F(AV)</sub>	30 A				
V <sub>R</sub>	600 V				
V <sub>F</sub> at I <sub>F</sub>	2.65 V				
t <sub>rr</sub> (typ.)	27 ns				
T <sub>J</sub> max.	175 °C				
Diode variation	Single die				

#### **FEATURES**

- · Hyperfast soft recovery time
- Low forward voltage drop
- 175 °C operating junction temperature
- Low leakage current



- True 2 pin package
- Compliant to RoHS Directive 2002/95/EC
- Halogen-free according to IEC 61249-2-21 definition
- Designed and qualified according to JEDEC-JESD47

### **DESCRIPTION/APPLICATIONS**

Hyperfast recovery rectifiers designed with optimized performance of forward voltage drop, hyperfast recovery time, and soft recovery.

The planar structure and the platinum doped life time control guarantee the best overall performance, ruggedness and reliability characteristics.

These devices are intended for use in PFC boost stage in the AC/DC section of SMPS, inverters or as freewheeling diodes.

The extremely optimized stored charge and low recovery current minimize the switching losses and reduce over dissipation in the switching element and snubbers.

ABSOLUTE MAXIMUM RATINGS					
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS	
Peak repetitive reverse voltage	V <sub>RRM</sub>		600	V	
Average rectified forward current in DC	I <sub>F(AV)</sub>	T <sub>C</sub> = 131 °C	30	А	
FULL-PAK		$T_{C} = 51 \ ^{\circ}C$	30		
Non-repetitive peak surge current	I <sub>FSM</sub>	T <sub>J</sub> = 25 °C	180		
Operating junction and storage temperatures	T <sub>J</sub> , T <sub>Stg</sub>		- 65 to 175	°C	

<b>ELECTRICAL SPECIFICATIONS</b> (T <sub>J</sub> = 25 °C unless otherwise specified)							
PARAMETER	SYMBOL	TEST CONDITIONS	TYP.	MAX.	UNITS		
Breakdown voltage, blocking voltage	V <sub>BR</sub> , V <sub>R</sub>	I <sub>R</sub> = 100 μA	600	-	-		
Forward voltage	V <sub>F</sub>	I <sub>F</sub> = 30 A	-	2.0	2.65		
Forward voltage		I <sub>F</sub> = 30 A, T <sub>J</sub> = 150 °C	-	1.4	1.8		
		$V_{R} = V_{R}$ rated	-	0.02	30		
Reverse leakage current $I_R$ $T_J = 150 \text{ °C}, V_R$		$T_J = 150 \ ^{\circ}C, V_R = V_R \text{ rated}$	-	50	300	μA	
Junction capacitance	CT	V <sub>R</sub> = 600 V	-	20	-	pF	
Series inductance	L <sub>S</sub>	Measured lead to lead 5 mm from package body	-	8	-	nH	

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RoHS COMPLIANT HALOGEN FREE

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<b>DYNAMIC RECOVERY CHARACTERISTICS</b> ( $T_J = 25$ °C unless otherwise specified)							
PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.	MAX.	UNITS
		$I_F = 1 \text{ A}, dI_F/dt = 50$	$I_F = 1 \text{ A}, \text{ d}I_F/\text{d}t = 50 \text{ A}/\mu\text{s}, \text{ V}_R = 30 \text{ V}$		26	35	
Reverse recovery time	t <sub>rr</sub>	T <sub>J</sub> = 25 °C	I <sub>F</sub> = 30 A dI <sub>F</sub> /dt = 200 A/μs V <sub>R</sub> = 200 V	-	26	-	ns
		T <sub>J</sub> = 125 °C		-	70	-	
Dook roooyony ourront		T <sub>J</sub> = 25 °C		-	3.5	-	Α
Peak recovery current	IRRM	T <sub>J</sub> = 125 °C		-	7.6	-	A
Deverse receiver above	Q <sub>rr</sub>	T <sub>J</sub> = 25 °C		-	50	-	nC
Reverse recovery charge		T <sub>J</sub> = 125 °C		-	280	-	

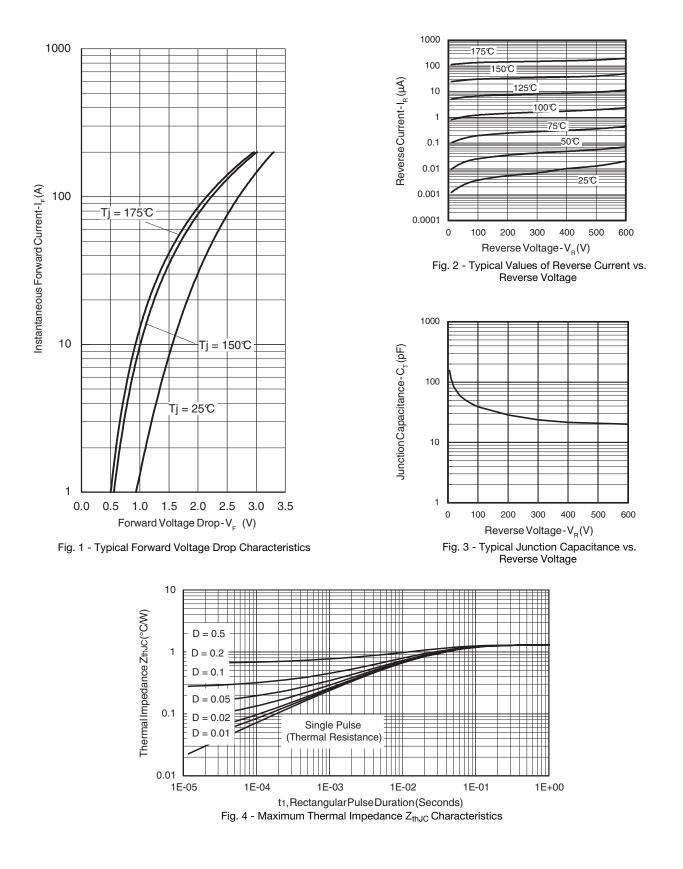
THERMAL - MECHANICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Maximum junction and storage temperature range	T <sub>J</sub> , T <sub>Stg</sub>		- 65	-	175	°C
Thermal resistance,	D		-	0.84	1.3	
junction to case FULL-PAK	R <sub>thJC</sub>		-	3.2	3.8	
Thermal resistance, junction to ambient	R <sub>thJA</sub>	Typical socket mount	-	-	70	°C/W
Typical thermal resistance, case to heatsink	R <sub>thCS</sub>	Mounting surface, flat, smooth and greased	-	0.5	-	
) M/-:			-	2	-	g
Weight			-	0.07	-	OZ.
Mounting torque			6 (5)	-	12 (10)	kgf · cm (lbf · in)
		Case style 2L TO-220AC ETH300		3006		
Marking device		Case style 2L TO-220 FULL-PAK		ETH3	006FP	

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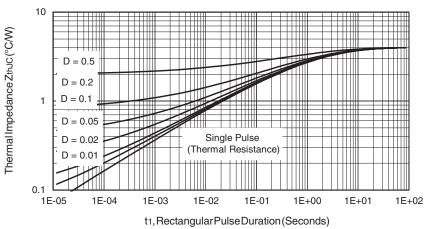
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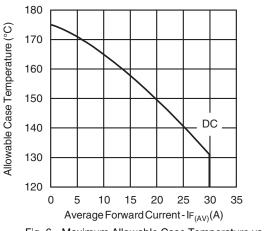
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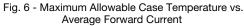
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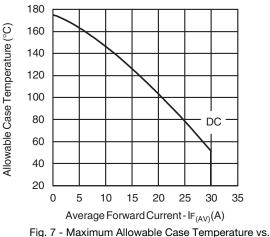


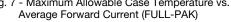


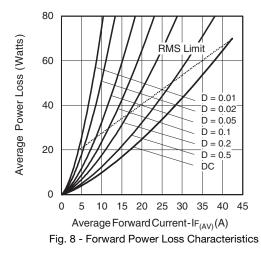










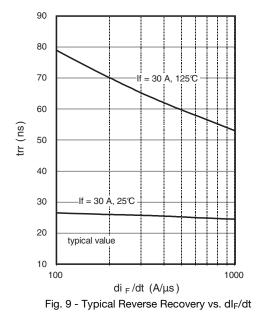


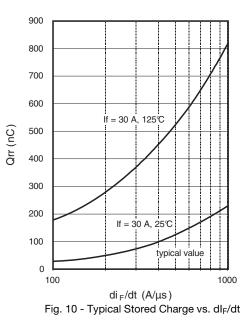


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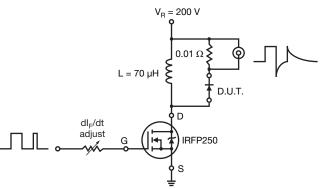
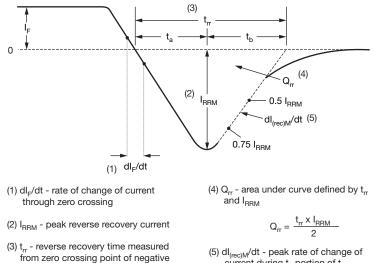


Fig. 11 - Reverse Recovery Parameter Test Circuit



(5)  $dI_{(rec)M}/dt$  - peak rate of change of current during t<sub>b</sub> portion of t<sub>rr</sub>

Fig. 12 - Reverse Recovery Waveform and Definitions

going I<sub>F</sub> to point where a line passing through 0.75  $\mathrm{I}_{\mathrm{RRM}}$  and 0.50  $\mathrm{I}_{\mathrm{RRM}}$ extrapolated to zero current.

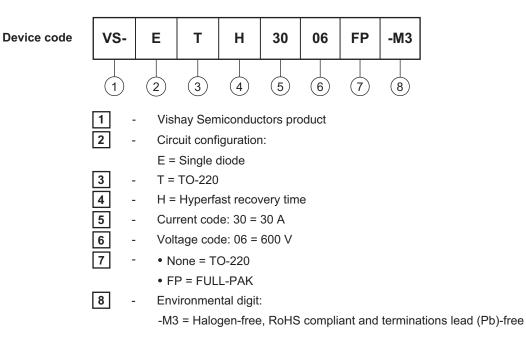
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### ORDERING INFORMATION TABLE



ORDERING INFORMATION (Example)						
PREFERRED P/N QUANTITY PER TUBE MINIMUM ORDER QUANTITY PACKAGING DESCRIPTION						
VS-ETH3006-M3	50	1000	Antistatic plastic tube			
VS-ETH3006FP-M3	50	1000	Antistatic plastic tube			

LINKS TO RELATED DOCUMENTS				
Dimensions	www.vishay.com/doc?95259			
Dimensions	2L TO-220 FULL-PAK	www.vishay.com/doc?95260		
Dart marking information	2L TO-220AC	www.vishay.com/doc?95391		
Part marking information	2L TO-220 FULL-PAK	www.vishay.com/doc?95392		

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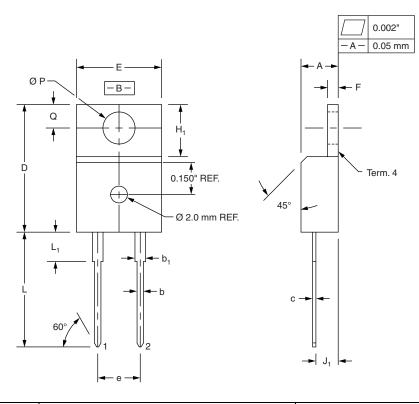




Din TO 220

# True 2 Pin TO-220

#### **DIMENSIONS** in millimeters and inches



SYMBOL	MILLIN	IETERS	INCH	ES
	MIN.	MAX.	MIN.	MAX.
A	4.32	4.57	0.170	0.180
b	0.71	0.91	0.028	0.036
b <sub>1</sub>	1.15	1.39	0.045	0.055
с	0.36	0.53	0.014	0.021
D	14.99	15.49	0.590	0.610
E	10.04	10.41	0.395	0.410
e	5.08	BSC	0.200 E	BSC
F	1.22	1.37	0.048	0.054
H <sub>1</sub>	5.97	6.47	0.235	0.255
J <sub>1</sub>	2.54	2.79	0.100	0.110
L	13.47	13.97	0.530	0.550
L <sub>1</sub> <sup>(1)</sup>	3.31	3.81	0.130	0.150
Ø P	3.79	3.88	0.149	0.153
Q	2.60	2.84	0.102	0.112

#### Notes

 $^{\left(1\right)}$  Lead dimension and finish uncontrolled in  $L_{1}$ 

• These dimensions are within allowable dimensions of JEDEC TO-220AB rev. J outline dated 3-24-87

Controling dimension: Inch

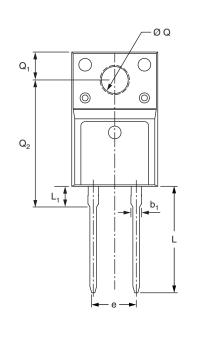


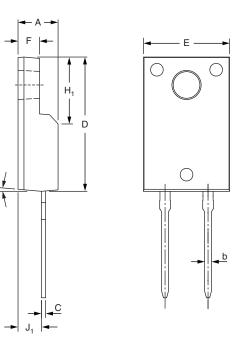


True 2 Pin TO-220 FULL-PAK

θ

#### **DIMENSIONS** in millimeters and inches





SYMBOL	MILLIN	METERS	INC	HES
STMDOL	MIN.	MAX.	MIN.	MAX.
A	4.53	4.93	0.178	0.194
b	0.71	0.91	0.028	0.036
b <sub>1</sub>	1.15	1.39	0.045	0.055
С	0.36	0.53	0.014	0.021
D	15.67	16.07	0.617	0.633
E	9.96	10.36	0.392	0.408
е	5.08	5.08 typical		typical
F	2.34	2.74	0.092	0.107
H <sub>1</sub>	6.50	6.90	0.256	0.272
J <sub>1</sub>	2.56	2.96	0.101	0.117
L	12.78	13.18	0.503	0.519
L <sub>1</sub>	2.23	2.63	0.088	0.104
ØQ	2.98	3.38	0.117	0.133
Q <sub>1</sub>	3.10	3.50	0.122	0.138
Q <sub>2</sub>	14.80	15.20	0.583	0.598
θ	0°	5°	0°	5°

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